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A Spin Coating Method to Deposit Iridium-Based Catalysts onto Silicon for Water Oxidation Photoanodes

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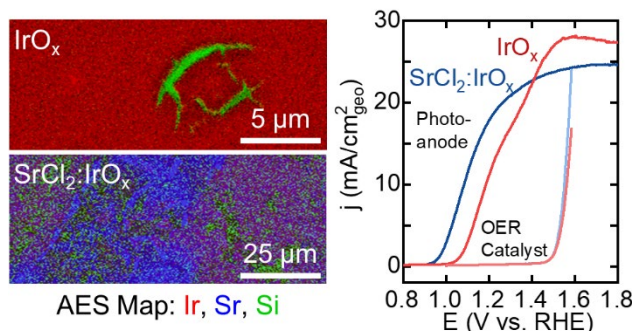
KEYWORDS

Photoelectrochemical water splitting, iridium oxide, oxygen evolution, photoanodes, spin coating

ABSTRACT

Silicon has shown promise for use as a small band gap (1.1 eV) absorber material in photoelectrochemical (PEC) water-splitting. However, the limited stability of silicon in acidic electrolyte requires the use of protection strategies coupled with catalysts. Herein, spin coating is used as a versatile method to directly coat silicon photoanodes with an IrO_x oxygen evolution reaction (OER) catalyst, reducing the processing complexity compared to conventional fabrication schemes. Biphasic strontium chloride/iridium oxide (SrCl₂:IrO_x) catalysts are also developed, and both catalysts form photoactive junctions with silicon and demonstrate high photoanode activity. The iridium oxide photoanode displays a photocurrent onset at 1.06 V vs. RHE, while the SrCl₂:IrO_x photoanode onsets earlier at 0.96 V vs. RHE. The differing potentials are consistent with the observed photovoltages of 0.43 V and 0.53 V for the IrO_x and SrCl₂:IrO_x, respectively. By measuring the oxidation of a reversible redox couple, Fe(CN)₆^{3-/4-}, we compare the charge carrier extraction of the devices and show that the addition of SrCl₂ to the IrO_x catalyst improves the silicon-electrolyte interface compared to pure IrO_x. However, the durability of the strontium-containing photoanode remains a challenge, with its photocurrent density decreasing by 90% over 4 hours. The IrO_x photoanode, on the other hand, maintained a stable photocurrent density over this timescale. Characterization of the as-prepared and post-tested material structure via Auger electron spectroscopy identifies catalyst film cracking and delamination as the primary failure modes. We propose that improvements to catalyst adhesion should further the viability of spin coating as a technique for photoanode preparation.

TOC GRAPHIC



TEXT

Introduction

Photoelectrochemical (PEC) water splitting is an attractive technology that uses sunlight to split water into hydrogen and oxygen, providing a storable chemical fuel to supplement intermittent renewable energy sources.¹⁻⁴ For PEC to become a viable means of sustainable hydrogen generation, the device must be highly efficient, durable, and cost-effective.⁵ Tandem-absorber devices, in which two semiconductor absorbers are stacked in series, are particularly relevant as they can achieve the high voltage needed to split water while generating a high photocurrent.^{1,2} To maximize device efficiency, photoelectrode materials need to be paired with an effective oxygen evolution reaction (OER) or hydrogen evolution reaction (HER) catalyst while minimizing parasitic light absorption.⁶ Often an additional protection layer such as a metal^{7,8}, metal oxide^{9,10}, or carbon nanomaterial^{11,12} is needed to prevent semiconductor corrosion by insulating the semiconductor from electrolyte contact. A range of photocathodes with varied semiconductor and catalyst materials have demonstrated high activity toward HER and stability in acidic electrolyte.⁶ In contrast, there are far fewer active stable photoanodes known due to the limited stability of most catalysts and semiconductors in acidic electrolyte at the oxidizing potentials of the OER.^{6,13}

Silicon is a desirable absorber for photoanodes due to its low cost, robust fabrication process, favorable band alignment with the OER, and near-ideal bandgap (1.1 eV) to pair with a wide-bandgap absorber.^{1,6} Several reports have shown that ultrathin TiO₂ coatings can effectively protect silicon from passivation and form efficient photoanodes when coated with an iridium OER catalyst.^{9,10,14–21} A recent report demonstrated that IrO_x/Ir sputtered onto p⁺n-Si without an additional protection layer produced 0.5-0.62 V of photovoltage and effectively protected the semiconductor for 18 hours of PEC operation with only moderate current loss.²² These protecting strategies utilized complex deposition techniques such as atomic layer deposition (ALD) and sputtering, which require sub-nanometer control of the protection layer thickness and structure to avoid performance losses due to increased device resistance in the TiO₂⁹ or decreased stability of the IrO_x.²² To facilitate the scale-up of PEC water-splitting, it is desirable to reduce processing complexity and decrease the sensitivity of anode performance on structural variables while maintaining high activity and long-term durability.

Of the known OER catalysts, only iridium oxide-based materials have demonstrated long-term stability at oxidizing potentials in corrosive acidic media.^{3,23–26} Herein, we focus on using a simple spin coating technique to deposit IrO_x OER electrocatalysts directly onto a silicon absorber to fabricate a photoanode junction, thereby minimizing the number and complexity of fabrication steps. In addition, recent work has shown that crystalline SrIrO₃ provides the highest known OER activity in acid on a catalyst surface-area basis.^{27,28} However, the pulsed laser deposition (PLD) synthesis for these SrIrO₃ catalysts requires an atomically flat, lattice-matched substrate as well as high deposition temperatures of 650°C, which limit the application of SrIrO₃ towards photoanodes.

Instead, this report develops a solution processing technique to combine iridium oxide with strontium for use as an OER catalyst.

In this work we report a spin coating method to deposit a pure IrO_x catalyst film onto silicon for use as a photoanode, reducing the processing complexity of conventional photoanodes. Strontium chloride-modified iridium oxide catalysts are also developed, and both catalyst films are characterized in terms of morphology, chemical distribution, and crystallography. The performance and stability of the photoanodes were tested for PEC water oxidation, and the effects of strontium on the Si/catalyst interface were evaluated using a reversible redox couple to decouple the catalysis from interfacial charge transport. Post-PEC testing characterization is used to identify degradation mechanisms. This study demonstrates the utility of spin coating as a simple, low cost fabrication technique to directly coat catalyst materials onto silicon photoanodes for PEC water-splitting. The photoanodes deliver high photovoltages that are comparable to those generated by state of the art ALD-protected Si photoanodes.^{9,19–21} The addition of strontium is shown to improve the charge carrier extraction properties of the silicon-catalyst-electrolyte junction, but the heterogeneous nature of the catalyst accelerates instability, which is associated with poor adhesion. Solution-processed photoanode materials have not previously been widely explored, and this work provides routes to simplify fabrication schemes for both silicon and other photoanodes, while the insight into degradation mechanisms can help guide the design of materials with improved stability.

Results & Discussion

Catalyst Structure

We synthesized photoanodes with a pure iridium oxide OER catalyst on Si architecture ($\text{IrO}_x|\text{n-Si}$) by spin coating a solution of iridium acetate onto a Si substrate followed by an air calcination at 250°C .^{29–31} Strontium-modified iridium oxide-coated Si photoanodes ($\text{SrCl}_2:\text{IrO}_x|\text{n-Si}$) were synthesized in an identical manner to IrO_x except the spin coating solution contained both iridium acetate and strontium chloride. Detailed procedures can be found in the materials and methods section. Scanning electron microscopy (SEM) and Auger electron spectroscopy (AES) were used to characterize the morphology and elemental distribution of both materials (Figure 1). Cross-sectional SEM imaging demonstrates that the IrO_x coating has a fairly uniform morphology and a thickness of 45 nm (Figure 1a). Top-down SEM confirms this general uniformity, although there are some cracks in the surface on the order of 0.5–5 μm in length (Figure 1b). Auger electron spectroscopy (AES) mapping indicates that the cracks go through the entirety of the spin-coated film and expose the bare silicon substrate (Figure 1c, S2). The X-ray diffractogram (Figure 2a) shows only broad peaks corresponding to rutile IrO_2 , indicating that the iridium oxide is primarily amorphous, which is consistent with previous reports of solution-processed iridium oxide calcined at 250°C .^{29–31}

The strontium-containing IrO_x film, referred to here as $\text{SrCl}_2:\text{IrO}_x$, is less uniform and conformal than the IrO_x film (Figure 1d). The morphology of the $\text{SrCl}_2:\text{IrO}_x$ as seen by SEM contains many macroscopic defects (Figure 1e, S1), with large stripes around 30 μm wide and many smaller cracks of less than 5 μm . AES mapping shows that there is phase segregation between Sr and Ir (Figure 1f), with the 30 μm stripe containing mostly Sr and all of the iridium residing in the remaining film area. Some of the small cracks on the order of 0.5–5 μm expose the Si substrate. Residual Cl species from the SrCl_2 precursor are co-located with the Sr (Figure S3). The co-

location of the Sr and Cl observed via AES suggests that there is a SrCl_2 phase separate from IrO_x . X-ray diffraction results (Figure 2b) confirm the presence of SrCl_2 , where the main diffraction peaks for the $\text{SrCl}_2:\text{IrO}_x$ film correspond to $\text{SrCl}_2 \cdot 6\text{H}_2\text{O}$, the thermodynamically stable hydrate of SrCl_2 at room temperature.³² There are weak, broad peaks corresponding to rutile IrO_2 , indicating that the iridium oxide in $\text{SrCl}_2:\text{IrO}_x$ is largely amorphous and phase segregated from SrCl_2 . The IrO_2 diffraction peaks for $\text{SrCl}_2:\text{IrO}_x$ are much weaker than those for IrO_x , suggesting that the iridium oxide is less crystalline in the strontium-containing catalyst film.

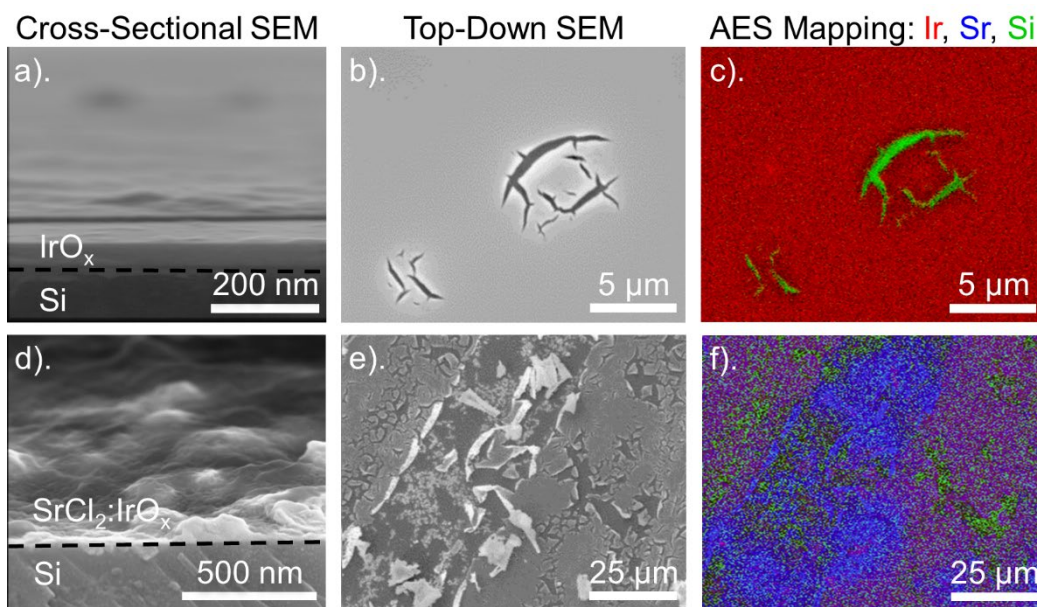


Figure 1. Photoanode characterization of $\text{IrO}_x/\text{n-Si}$ (a-c) and $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ (d-f). Cross-sectional SEM (a,d) shows that the IrO_x catalyst has a uniform morphology, while the $\text{SrCl}_2:\text{IrO}_x$ has greater surface roughness. Dashed lines indicate the boundary between the catalyst film and the Si substrate. Top-down SEM (b,e) shows cracking and heterogeneity in the films. AES mapping (c,f) of Ir (red), Sr (blue), and Si (green) shows that there is exposed silicon in the cracks for both catalysts, while there is extensive phase segregation in the $\text{SrCl}_2:\text{IrO}_x$ coating.

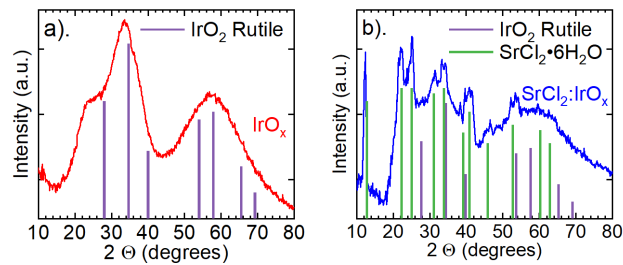


Figure 2. X-ray diffractograms (background subtracted) of IrO_x (a) and SrCl₂:IrO_x (b). The broad diffraction peaks for IrO_x indicate that the material is mostly amorphous, and the limited crystallinity comes from rutile IrO₂. The SrCl₂:IrO_x film has SrCl₂ • 6H₂O features, suggesting phase segregated SrCl₂•6H₂O. Reference patterns used: 00-015-0870 (IrO₂ rutile), 04-010-2886 (SrCl₂•6H₂O). The raw XRD patterns can be seen in Figure S4.

To investigate phase segregation between IrO_x and SrCl₂ in SrCl₂:IrO_x, SEM was performed after each step of the deposition process: (1) after spin coating only (Figure S5a); (2) following spin coating and a 50 °C hot plate treatment (Figure S5b); and lastly (3) the end of fabrication – spin coating, hot plate treatment, and calcination at 250 °C (Figure S5c). Apparent phase segregation and cracking are visible immediately after spin coating, indicating that this process likely induces phase segregation between Sr and Ir, which is retained during the heat treatments. During the spin coating procedure, SrCl₂ and Ir(CH₃COOH)₃ are dissolved in 5% v/v water in ethanol to facilitate both solubility of SrCl₂ and fast evaporation during the spin coating process. We note that the solubility of SrCl₂ is ~20 g/L (0.11 M) in 5% water in ethanol, as opposed to >500 g/L (>3.2 M) in water.³² We postulate that the low solubility of SrCl₂ in ethanol drives the phase segregation between IrO_x and SrCl₂ • 6H₂O in the highly heterogeneous SrCl₂:IrO_x film. As the solvent film begins to evaporate during spin coating, the Sr and Ir precursors become

increasingly concentrated, potentially causing the SrCl_2 to become supersaturated and thus precipitate out of solution.^{33,34} This rapid precipitation of SrCl_2 likely leads to the striped and heterogeneous morphology seen in Figure 1e. This effect has been previously been observed in substituted fullerene films deposited by spin coating, where different functional groups on solvated fullerenes change the solubility and greatly impact the film morphology.³⁵

Photoelectrochemical Testing

i. Photoanode Activity

The photoelectrochemical behavior of $\text{IrO}_x/\text{n-Si}$ and $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ were evaluated in 0.5 M H_2SO_4 electrolyte under one-sun illumination and in the dark via cyclic voltammetry (CV) (Figure 3a,c). Both catalyst coatings formed effective junctions with silicon, as is evidenced by the photocurrent onset potential of 1.06 V vs. RHE for $\text{IrO}_x/\text{n-Si}$ and 0.96 V vs. RHE for $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$. The current onset potential is defined as the potential required to reach a threshold current density of 1 mA/cm^2 . Both photoanodes exhibit photocurrent onset potentials negative of the reversible potential for OER (1.23 V vs. RHE). The native SiO_2 layer (1.8 nm) is thin enough to allow for hole tunneling, consistent with prior reports on n Si photoanodes with thin SiO_2 and/or TiO_2 layers.^{19,36,37} The $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ anode has a slightly higher fill factor than $\text{IrO}_x/\text{n-Si}$, indicating that it has a lower resistance to charge transport across the Si-catalyst-electrolyte interface, assuming both photoanodes have similar catalysis and given the identical semiconductors. The dark current for both photoanodes is negligible across the potential range scanned. To understand the difference in performance between these two photoanode systems without complication from the silicon absorber or rectifying semiconductor-catalyst junction, we tested the OER performance of catalyst films deposited onto degenerately doped silicon ($\text{p}^+\text{-Si}$).

The strontium-containing catalyst has slightly higher raw catalytic activity than IrO_x alone as seen in the potential required to reach a current density of 10 mA/cm^2 , a common metric of OER activity.^{24,25} $\text{SrCl}_2:\text{IrO}_x|\text{p}^+\text{-Si}$ requires 1.55 V vs. RHE (0.32 V of overpotential) to generate 10 mA/cm^2 of current density, while $\text{IrO}_x|\text{p}^+\text{-Si}$ requires 1.56 V vs. RHE (0.33 V of overpotential). Thus, the addition of strontium chloride to the IrO_x OER catalyst decreases the overpotential required to reach 10 mA/cm^2 by 0.01 V .

One key metric of photoanode performance is the photovoltage (V_{ph}), which is calculated as the difference in the potential of current onset between the photoanode and the corresponding dark electrocatalyst.¹⁹ Notably, the photovoltage of the $\text{SrCl}_2:\text{IrO}_x|\text{n-Si}$ is 0.53 V , or 0.10 V greater than that of the $\text{IrO}_x|\text{n-Si}$ system (0.43 V).

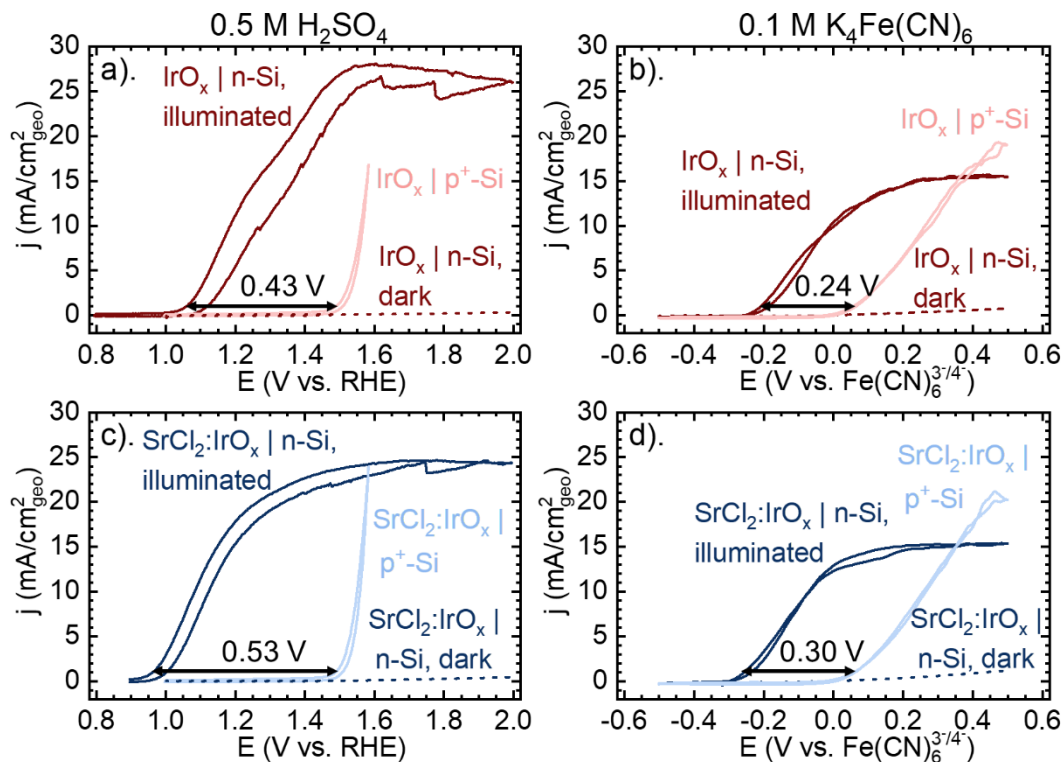


Figure 3. Photoelectrochemical testing results. Water oxidation testing (a,c) is conducted in 0.5 M H₂SO₄. CVs in 0.1 M Fe(CN)₆^{3-/4-} (b,d) decouple catalytic performance from light absorption and charge transport. Photovoltage (V_{ph}) values are calculated by the difference in potential of current onset between the anodic sweeps of the n-Si photoanode and corresponding OER catalyst. The black arrows indicate the two current onset potentials, where the line length represents the V_{ph} , noted above each arrow. All CVs are measured with a scan rate of 10 mV/s.

PEC testing was also conducted in a solution of 0.1 M K₄Fe(CN)₆ and 1 mM K₃Fe(CN)₆ (Figure 3b,d), a reversible redox couple, to decouple catalytic effects from light absorption and charge separation.²⁰ Both catalyst films deposited onto p⁺-Si substrates showed similar J-V characteristics, consistent with the expected facile one-electron redox process at a conductive substrate. SrCl₂:IrO_x|n-Si gave 0.30 V of V_{ph} during ferrocyanide oxidation, compared to 0.24 V for IrO_x|p⁺-Si. The photoanodes produced less photovoltage during ferrocyanide oxidation than for water oxidation, which suggests that the electrolyte redox couple is in ionic contact with the Si-catalyst junction. Nevertheless, SrCl₂:IrO_x|n-Si generates a higher V_{ph} than IrO_x|n-Si under both OER and Fe(CN)₆^{3-/4-} conditions. The photovoltage measurements are supported by the open circuit potential (OCP) in the dark and under illumination, measured in both sulfuric acid and potassium ferrocyanide electrolytes measured in the dark and under illumination (Figure S8).³⁸ The light-limited photocurrent is approximately the same for both IrO_x|n-Si and SrCl₂:IrO_x|n-Si, around 15 mA/cm², meaning that light absorption in the two catalyst films is similar. Thus, we postulate that SrCl₂:IrO_x facilitates improved charge carrier transport across the Si-catalyst-electrolyte interface compared to IrO_x, leading to its improved photovoltage. Photoanodes with thinner catalyst films than those measured in Figures 1-5 were also tested, exhibiting a higher potential of current onset

and lower V_{ph} than the thickest films, likely due to differences in catalyst performance and interfacial charge transport (Figure S9).

Interestingly, after testing the films for three cyclic voltammetry cycles under illumination, XPS measurements indicate that the Ir near the surface becomes more oxidized in both photoanode architectures and that $SrCl_2$ dissolves from the $SrCl_2:IrO_x$ film in the surface region (Figure S6, S7). Despite the dissolution of $SrCl_2$, the photoanodes still produce stable current over the timescale of three CV cycles. Because $SrCl_2$ is not present in the catalyst during PEC operation, this salt likely plays little direct role in the improved performance of the photoanodes. Instead, we propose that the rough, porous morphology of the $SrCl_2:IrO_x$ coating improves the electronic interface with Si and charge transport to the electrolyte over the more planar IrO_x . Prior experimental and theoretical studies on WO_3 semiconductors coated with IrO_2 catalyst films showed that conformal IrO_2 coatings formed a junction with WO_3 that resulted in poor interfacial charge transport and thus low photoanode activity.^{39,40} Conversely, rougher, more porous IrO_2 catalyst films allow the electrolyte to contact both the catalyst and semiconductor, which shifts the relative positions of the IrO_2 Fermi level and semiconductor conduction band minimum, facilitating hole extraction to the electrolyte and thus OER catalysis.^{39,40} We propose a similar effect in these silicon photoanodes: both photoanodes have some degree of cracking in the catalyst layer and thus have some silicon-electrolyte contact. Importantly, the $SrCl_2:IrO_x|n-Si$ has a rougher surface with more cracks, causing more Si-electrolyte interaction than $IrO_x|n-Si$. This semiconductor-catalyst-electrolyte contact is hypothesized to improve hole transport across the interface in $SrCl_2:IrO_x|n-Si$ compared to $IrO_x|n-Si$.

State of the art photoanodes, such as those based on ultrathin coatings of ALD-deposited TiO_2 on Si, generate 0.5-0.6 V of photovoltage in acidic electrolyte.^{9,14,19–21,41,42} It is notable that the photovoltages reported here are in line with those of TiO_2 -protected photoanodes, but the fabrication scheme presented here is much simpler and less sensitive than the ALD procedures used in the field and does not need a silicon homojunction for photoactivity, which could allow for better integration with photocathodes.

ii. Photoanode Stability

In addition to high activity, an effective photoanode must also have long-term stability. We first measured the durability of the catalysts on degenerately doped silicon **after an initial CV measurement and brief (~30 min) air exposure** by performing one CV sweep followed by a 30 minute chronoamperometry (CA) measurement, repeated over 7 hours (Figure 4). The CA behavior was monitored at 1.57 V vs. RHE, the initial potential needed for IrO_x to reach 10 mA/cm^2 in the first CV sweep. $\text{SrCl}_2\text{:IrO}_x$ initially has ~20% higher current than IrO_x as seen in both the anodic CV sweeps and CA current during the first 30 min hold. However, after around 3 h, the current densities of both catalysts decreased to nearly the same value, with IrO_x losing 40% of its initial current density, and $\text{SrCl}_2\text{:IrO}_x$ losing 60%. After 3 h of testing, the current densities approach a stable value, and degradation is much slower than the initial rate.

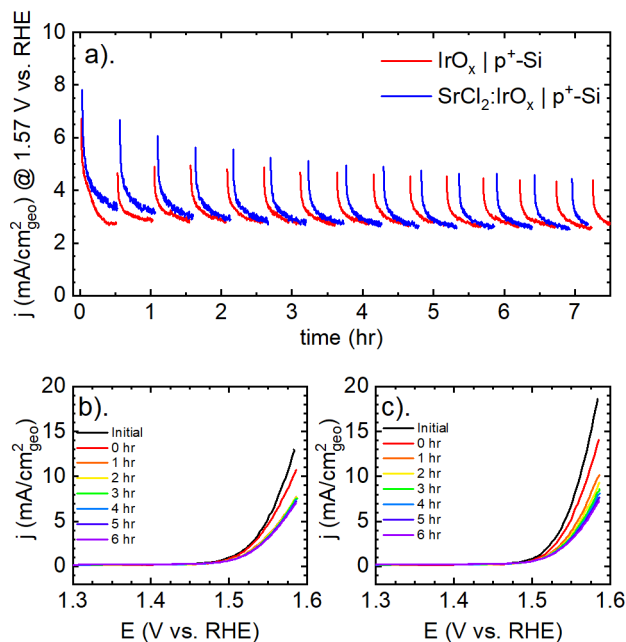


Figure 4. OER catalyst stability. Chronoamperometric testing of the catalysts on degenerately doped (p⁺) Si at 1.57 V vs. RHE (a). Anodic sweeps taken with a scan rate of 10 mV/s every ~1 hour for IrO_x (b) and SrCl₂:IrO_x (c). SrCl₂:IrO_x has improved activity compared to IrO_x but the degradation rates are similar.

To investigate the stability of the photoanodes, we used a similar protocol to that used above for the OER catalyst stability: after an initial CV measurement and brief air exposure we measured a CV sweep followed by 30 minutes of chronoamperometry at 1.3 V vs. RHE, repeated over 4-20 hours (Figure 5). At a potential of 1.3 V vs. RHE, the current density is just below the light-limited current density and is the potential where the photoanode would generate its maximum power.^{1,6} The IrO_x photoanode maintained its current density for approximately 4 h, and actually increased from 17 mA/cm² to a peak of 19 mA/cm² after 3 h (Figure 5a). This increase in photocurrent correlates with an increase in light-limited current density as seen in the LSVs (Figure 5b), from

26 mA/cm² to 32 mA/cm² after 9 hours of testing. The light-limited current density likely increases due to the IrO_x film material degrading/delaminating (See Figure 6), thereby reducing parasitic light absorption in the catalyst layer. For the same photoanode, the onset potential observed in the LSVs continuously shifted to a more positive potential throughout the duration of the stability test (Figure 5b), indicating that the photovoltage started decreasing immediately. This loss in photovoltage contributes to decreasing current at 1.3 V vs. RHE. These two effects that occur with degradation of the IrO_x catalyst and interface – decreased parasitic light absorption and decreased catalytic performance – combine to produce the observed photocurrent behavior. Namely, there is initially a slight increase in photocurrent during the first 3 h due to an increase in the light-limited current density. At later times, the photovoltage decreases enough to cause a rapid decrease in the current produced at 1.3 V vs. RHE.

On the other hand, the strontium chloride-modified photoanode was significantly less stable than the iridium oxide photoanode, with the photocurrent density decreasing almost immediately and losing 90% of its photocurrent after a 4 h potential hold at 1.3 V vs. RHE. (Figure 5a). In the LSVs the onset potential decreased quickly (Figure 5c), indicating that there was a loss in the amount of photovoltage being generated and thus rapid degradation of the photoanode. While the light-limited current density does increase slightly, the more rapid loss in photovoltage decreases the current density at 1.3 V vs. RHE measured in the CA. While neither photoanode exhibited long-term stability, IrO_x|n-Si maintained a high current density at 1.3 V vs. RHE for 4 h before abrupt degradation.

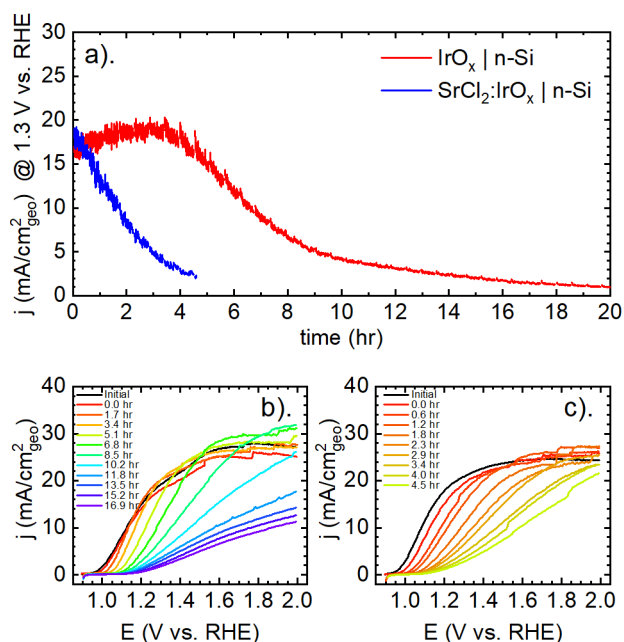


Figure 5: Photoanode stability. Chronoamperometric testing of the catalysts on degenerately doped Si at 1.3 V vs. RHE (a). A CV was measured with a scan rate of 10 mV/s every 30 minutes during the stability test, and selected anodic sweeps are shown for IrO_x (b) and SrCl₂:IrO_x (c). SrCl₂:IrO_x degradation commences immediately, while IrO_x|n-Si lasts for 4 h before degradation.

Post-Test Characterization

After the photoanode CA stability tests of 20 hours for IrO_x|n-Si and 5 hours for SrCl₂:IrO_x|n-Si, structural characterization of the thin films was performed using SEM and AES to probe the failure mechanisms of the catalyst films (Figure 6). The SEM images of the IrO_x|n-Si sample show large cracks that develop during testing and grow to be 0.5-5 μm wide (Figure 6a), and sections of the film appear to delaminate (Figure 6b). AES was measured at the specific points (Figure 6c) indicated on Figure 6b. The Auger spectra show that there are large regions where bare silicon is

exposed (spot 2) as well as flakes of IrO_x that appear to be delaminating (spot 3) from the main film (spot 1). Iridium has been shown in previous reports to have poor adhesion to SiO_2 .^{41,42} Thus, we propose that the degradation pathway is likely an expansion of the initial film cracks followed by delamination as opposed to chemical dissolution.

$\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ also showed extensive cracks on the order of 0.1-1 μm wide, smaller than those in the IrO_x coating (Figure 6d). These small-scale cracks match the size scale of the cracks in the as-deposited film (Figure 1f), so the degradation likely initiated at these defects. The striped morphology was retained after testing (Figure 6e), which originated from the phase segregation between SrCl_2 and IrO_x . After the SrCl_2 quickly dissolves (as seen in the XPS after three CVs, Figure S7), the 10-20 μm -wide stripes remain as alternating thick and thin regions of IrO_x (Figure 6f, with points indicated on Figure 6e), which is seen in the AES data at point 5 (stronger Ir signal) and point 6 (weaker Ir signal) of Figure 6e. There are also regions of exposed Si (Figure 6e,f). None of the spectra show any Sr or Cl, which is expected as there is very little SrCl_2 detected by XPS after only 3 CVs (Figure S7). $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ likely undergoes faster delamination than $\text{IrO}_x/\text{n-Si}$ as the strontium chloride-containing film initially has more cracks, is significantly less conformal, and has more electrolyte contact than the pure iridium oxide. This rapid delamination likely leads to the decreased PEC stability of $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ compared to $\text{IrO}_x/\text{n-Si}$ despite the higher initial activity. While film delamination limited photoanode stability, some catalyst material remained in contact with the Si after 4 and 20 h of PEC operation, for $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ and $\text{IrO}_x/\text{n-Si}$, respectively, as seen by both the post-test SEM images and the continued photocurrent generation at the end of testing. Improving catalyst-semiconductor adhesion would likely improve the stability of these photoanodes and thus further the viability of these spin coating procedures

for PEC systems. In addition, the advances this work demonstrate a means to improve the electronic interface between silicon and the catalyst by modifying IrO_x with SrCl_2 , which further motivate efforts to stabilize these photoanodes. With improved stability, this tunable spin coating method offers a pathway to simplify photoelectrode fabrication processes.

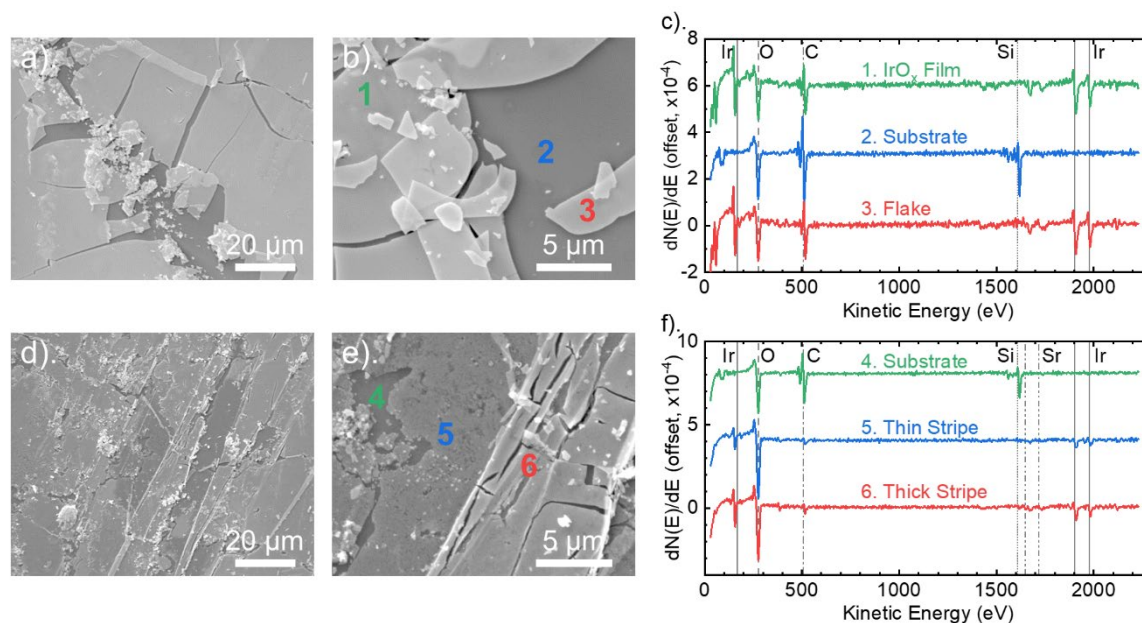


Figure 6. SEM and Auger spectroscopy post-stability testing for $\text{IrO}_x/\text{n-Si}$ (a-c) and $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ (d-f). Large-area SEM images (a,d) show cracking that develops during testing. Smaller-area SEM images (b,e) are subsets of a,d. Auger spectra (c,f) of selected points in the smaller SEM images were collected, with peaks for the relevant elements indicated with gray vertical lines. The points at which Auger analysis was performed are indicated with the relevant number in b and e.

Conclusion

In this work a spin coating procedure was developed to prepare iridium oxide-based catalyst coatings onto silicon for use as photoanodes for PEC hydrogen production in acid. The photoanode with an IrO_x catalyst formed a functioning photoanode, and the addition of strontium chloride to the catalyst coating improved PEC performance. In comparison to the 0.43 V of photovoltage

generated by $\text{IrO}_x/\text{n-Si}$, the $\text{SrCl}_2:\text{IrO}_x/\text{n-Si}$ photoanode prepared by this method demonstrated an improved photovoltage of 0.53 V. These photoanodes exhibited comparable J-V performance to more conventional silicon photoanodes with a separate ALD-deposited TiO_2 protection layer^{9,19–21}, thus demonstrating a pathway to reduce the number and intricacy of processing steps for future PEC water-splitting systems. By conducting ferrocyanide oxidation, we decoupled the interfacial charge transport from catalysis, indicating that the more heterogeneous film caused by strontium chloride precipitation improved the interfacial charge transport across the silicon-electrolyte interface. The stability of the catalysts and photoanodes were investigated, with the IrO_x photoanodes lasting for 4 hours before degrading and the $\text{SrCl}_2:\text{IrO}_x$ samples degrading within the first 4 hours. From post-testing characterization, consisting of AES, SEM, and XPS analysis, we determined that film cracking and delamination led to accelerated degradation. To improve photoelectrode longevity, attention must be given to catalyst adhesion. Due to their simple, tunable nature, the spin coating procedures developed here can be translated to other photoanode materials and tandem absorber systems. The beneficial charge transport properties of a rough, strontium-containing catalyst can also be leveraged in other PEC systems limited by poor electronic interfaces. Overall, this spin coating method has the potential to decrease PEC electrode fabrication cost and complexity compared to conventional CVD- and PVD-based photoanode fabrication while maintaining a high photovoltage, important characteristics when designing a tandem absorber system.

Materials and Methods

Photoanode Fabrication

Single crystal phosphorous-doped n-type silicon (100) wafers with resistivity of 0.2-0.6 Ω -cm were used as photoanode absorbers and are referred to here as n-Si (100 mm diameter, 525 μ m thick, EL-CAT Inc.). Boron-doped p-type silicon (100) wafers with <0.005 Ω -cm resistivity were used (100 mm diameter, 500 μ m thick, WRS Materials), referred to as p⁺-Si, and were used as substrates to compare OER catalytic properties. All wafers were cleaned by sonication in soapy water, acetone, isopropanol, and deionized water prior to electrode fabrication and other otherwise were used as-received.

Catalyst layers on silicon substrates were prepared using an adapted version of a previously-reported spin coating procedure.²⁹⁻³¹ A Brewer Science CEE 200X spin coater was employed. The IrO_x spin coating solution contained 20 g/L (0.054 M) iridium acetate (99%, American Elements) dissolved in ethanol (absolute, Acros). The solution for the SrCl₂:IrO_x film had an equimolar (0.054 M) mixture of iridium acetate and strontium chloride (99.99%, Acros) dissolved in 5% v/v water (Millipore) in ethanol. For film deposition, 40 μ L of solution was applied while the substrate was rotating at 200 rpm to maximize coverage. Then the substrate rotation rate was increased to 2000 rpm, accelerating at 200 revolutions/s², spinning for 60 s, after which point there was a dry thin film on the Si surface. The chip was then heated on a 50 °C hotplate for 5 minutes to evaporate any residual solvent. Finally, the electrodes were calcined in a pre-heated furnace (Thermolyne) at 250 °C for two hours in ambient air.

Sibling samples were deposited on fused silica pieces (MTI Corporation, 10x10x1.0 mm, 1 side polished) and were used for crystallography measurements due to their amorphous nature. The spin coating and calcination procedure was the same as that for the silicon substrate samples.

Materials Characterization

Cross-sectional and top-down scanning electron microscopy (SEM) (FEI Magellan 400 XHR) was used to measure film thickness and probe morphology. The native oxide thickness was estimated to be 1.8 nm with spectroscopic ellipsometry (Woollam M2000). Auger electron spectroscopy (AES) analysis was used to map the distribution of chemical constituents and was performed with a 10 kV/10 nA electron gun beam (PHI 700 Scanning Auger Nanoprobe). X-ray diffraction (XRD) (Bruker Single Crystal D8 Venture) was performed in a grazing-incidence configuration with a 2D detector to probe the crystallinity of the catalyst films. X-ray photoelectron spectroscopy (XPS) (PHI 5000 Versaprobe 1) was used to identify the relative abundance of oxygen, iridium, strontium, chlorine, and sulfur, probing the O 1s, Ir 4f, Sr 3d, Cl 2p, and S 2p peaks. XPS spectra were calibrated to the C 1s peak with a binding energy of 284.8 eV.

Photoelectrochemical Testing

Electrochemical measurements were performed in a standard three-electrode flat-faced quartz cell with a Hg/HgSO₄ (sat'd K₂SO₄) reference electrode and a Pt wire counter electrode. Electrochemical OER testing was conducted in 0.5 M sulfuric acid (diluted from concentrated sulfuric acid 99.999%, Sigma Aldrich) electrolyte. Oxygen gas was bubbled through the electrolyte, and a magnetic stir bar spinning at 350 rpm underneath the working electrode was employed to enhance bubble detachment. All cyclic voltammetry was performed at a scan rate of 10 mV/s. PEC testing was also conducted in electrolyte containing a reversible redox couple, Fe(CN)₆³⁻ / Fe(CN)₆⁴⁻. This electrolyte solution was prepared by dissolving 0.1 M K₄Fe(CN)₆ • 6H₂O (99%+,

Acros) and 1 mM $\text{K}_3\text{Fe}(\text{CN})_6$ (99%+, Acros) in water (pH 8.5). Ferrocyanide oxidation data was smoothed using a 10-point adjacent-averaging method in OriginPro 2018 software.

Photoelectrochemical measurements used a 100 W Xe arc lamp solar simulator (SunLite, Abet Technologies) calibrated to the AM 1.5G spectrum.⁴³ A spectrometer (Jaz EL 200-XR1, Ocean Optics) was used to measure the flux of photons with energy exceeding the bandgap of silicon ($\lambda < 1107$ nm), and the lamp was calibrated such that the total number of photons with $\lambda < 1107$ nm was equal to that of the AM 1.5G spectrum for $\lambda < 1107$ nm.

Electrodes were prepared from the silicon wafers by forming an electrical contact on the backside of the silicon by scratching Ga-In eutectic (>99.99%, Sigma-Aldrich) applied with a diamond scribe and attaching a wire to the Ga-In with carbon Electrodag (DAG-502, Ted Pella). The exposed wire and back/sides of the silicon were covered with epoxy (Hysol Loctite 9462). Electrode areas were measured with a digital photograph and analyzed using ImageJ, with areas ranging from 0.1-0.2 cm^2 .

ASSOCIATED CONTENT

Supporting Information.

The following files are available free of charge.

Additional material characterization (SEM, AES, XRD, XPS) and electrochemical characterization (open circuit potential measurements) (PDF)

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